

Table of Contents

Hydrogenated Amorphous Silicon

1. **Introduction**
 - History and development of hydrogenated amorphous silicon (a-Si:H)
 - Role of hydrogen in defect passivation
2. **Growth and Structure of Amorphous Silicon**
 - Deposition techniques (PECVD, glow discharge)
 - Atomic structure and Si-H bonding
3. **The Electronic Density of States**
 - Band structure
 - Localized states in the bandgap
 - Band-tail states
4. **Defects and Their Electronic States**
 - Dangling bonds
 - Electronic defect centers and trapping states
5. **Substitutional Doping**
 - p-type and n-type doping
 - Influence of dopants on electrical properties
6. **Defect Reactions, Thermal Equilibrium and Metastability**
 - Staebler–Wronski effect
 - Defect creation and annealing mechanisms
7. **Electronic Transport**
 - Carrier transport mechanisms
 - Hopping conduction and mobility
8. **Recombination of Excess Carriers**
 - Carrier recombination processes
 - Carrier lifetime
9. **Contacts, Interfaces and Multilayers**
 - Metal-semiconductor contacts
 - Heterojunctions and multilayer structures
10. **Amorphous Silicon Device Technology**
 - Thin-film solar cells
 - Photodetectors
 - Thin-film transistors (TFTs)
 - Large-area electronic applications